

View Online at <https://aerobasegroup.com/nsn/5961-01-292-2092>

Inclosure Material:

Metal

Overall Length:

0.250 inches

Overall Height:

0.100 inches

Overall Width:

0.250 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open all transistor and 50.0 breakdown voltage, collector-to-emitter, base open all transistor and 5.0 breakdown voltage, emitter-to-base, collector open all transistor

Current Rating Per Characteristic:

3.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector absolute all transistor

Transfer Ratio:

30.0 static forward current transfer ratio, common-emitter all transistor and 150.0 static forward current transfer ratio, common-emitter all transistor

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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